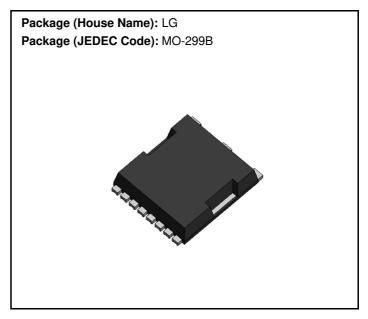
P232LG10GNK

Power MOSFETs 100V, 232A, N-channel

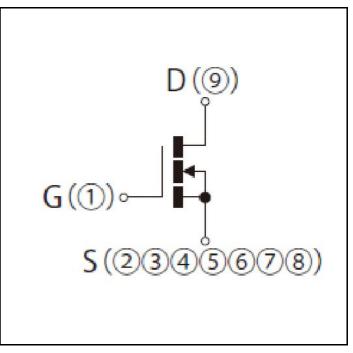
Feature

- N-channel
- SMD
- Super Large Current
- Low Ron
- 10V Gate Drive
- Low Capacitance
- · Based on AEC-Q101
- Halogen free
- Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit	
Storage temperature	Tstg		-55 to 175	°C	
Channel tempertature	Tch		-55 to 175	°C	
Drain-source voltage	V _{DSS}		100	V	
Gate-source voltage	V _{GSS}		±20	V	
Continuous drain current(DC)	I _D		232	А	
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, Duty=1/100	696	А	
Continuous source current(DC)	ls		232	А	
Total power dissipation	P _T	With heatsink	441	W	
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	85	A	
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	361	mJ	

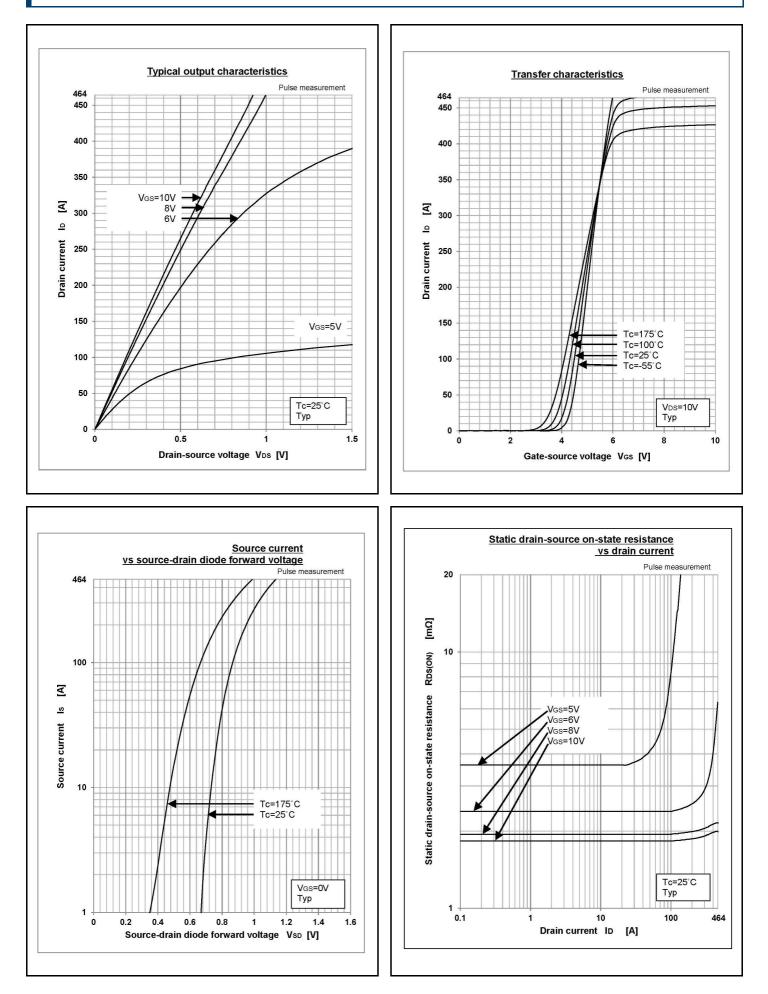
* : See the original Specifications

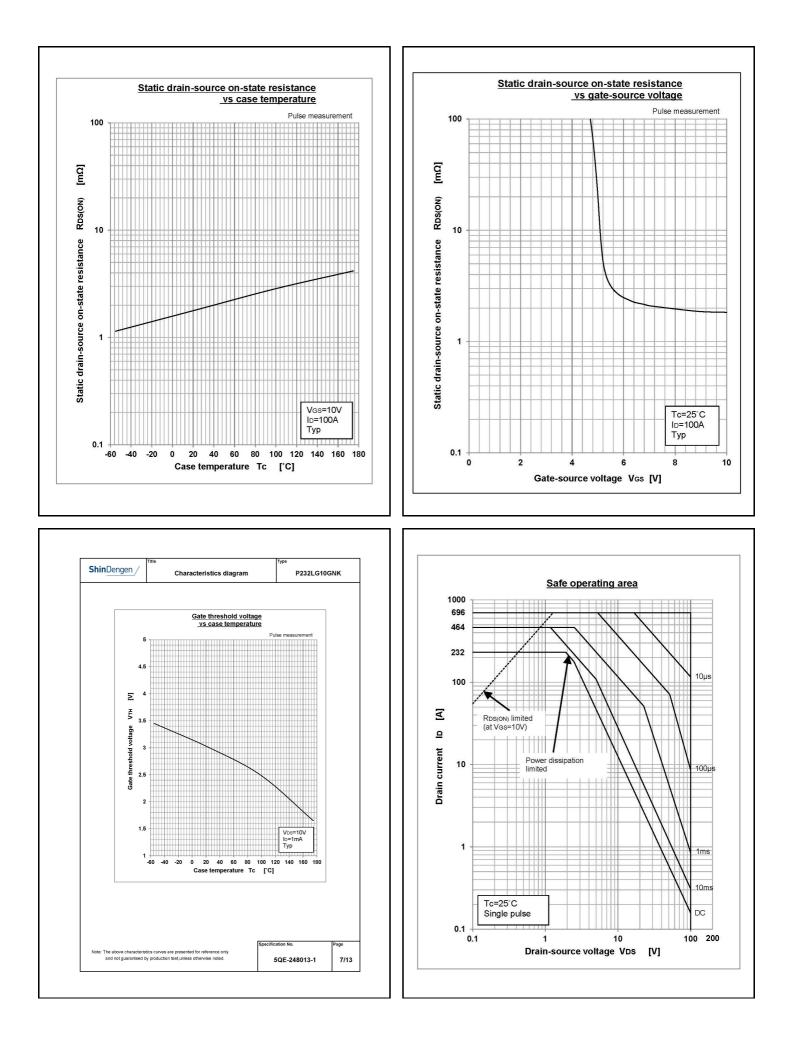
Electrical Characteristics

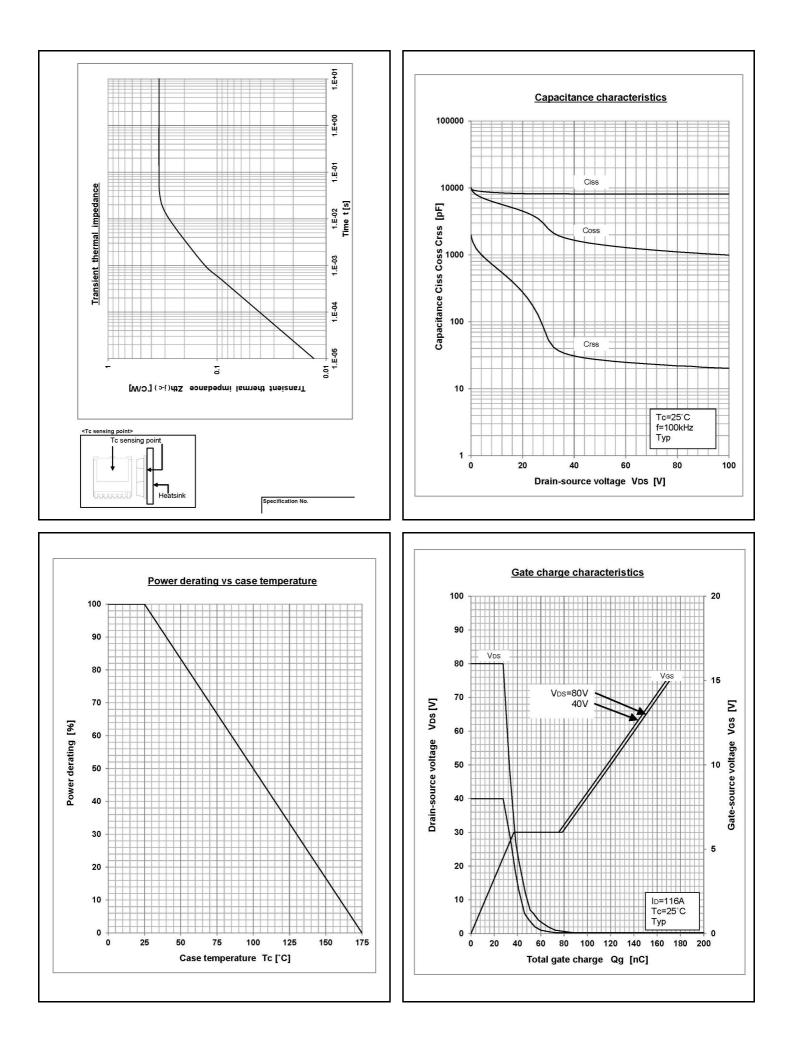
Item	Symbol	Conditions	Ratings			Unit
			MIN	ТҮР	MAX	Unit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	100			V
Zero gate voltage drain current	I _{DSS}	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g fs	ID=58A, VDS=10V	45			S
Static drain-source on-state resistance	R _{DS(ON)}	ID=100A, VGS=10V		0.00183	0.0022	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V_{SD}	IS=100A, VGS=0V			1.2	V
Thermal resistance	Rth(j-c)	Junction to case, With heatsink			0.34	°C/W
Total gate charge	Qg	VDS=80V, VGS=10V, ID=116A		120		nC
Gate to source charge	Qgs	VDS=80V, VGS=10V, ID=116A		36		nC
Gate to drain charge	Qgd	VDS=80V, VGS=10V, ID=116A		43		nC
Input capacitance	Ciss	VDS=50V, VGS=0V, f=100kHz		8140		pF
Reverce transfer capacitnce	Crss	VDS=50V, VGS=0V, f=100kHz		27		pF
Output capacitance	Coss	VDS=50V, VGS=0V, f=100kHz		1425		pF
Turn-on delay time	td(on)	ID=50A, RL=1Ω, VDS=50V, Rg=0Ω, +VGS=10V, - VGS=0V		16		ns
Rise time	tr	ID=58A, RL=0.86Ω, VDS=50V, Rg=0Ω, +VGS=10V, -VGS=0V		16		ns
Turn-off delay time	td(off)	ID=58A, RL=0.86Ω, VDS=50V, Rg=0Ω, +VGS=10V, -VGS=0V		37		ns
Fall time	tf	ID=58A, RL=0.86Ω, VDS=50V, Rg=0Ω, +VGS=10V, -VGS=0V		16		ns
Diode reverse recovery time	trr	IS=116A, VGS=0V, -di/dt=100A/µs		99		ns
Diode reverse recovery charge	Qrr	IS=116A, VGS=0V, -di/dt=100A/µs		241		nC

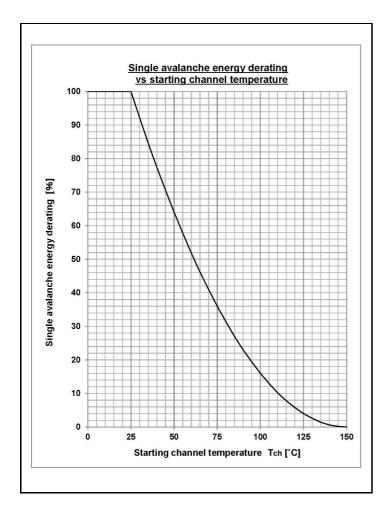
* : See the original Specifications

CHARACTERISTIC DIAGRAMS



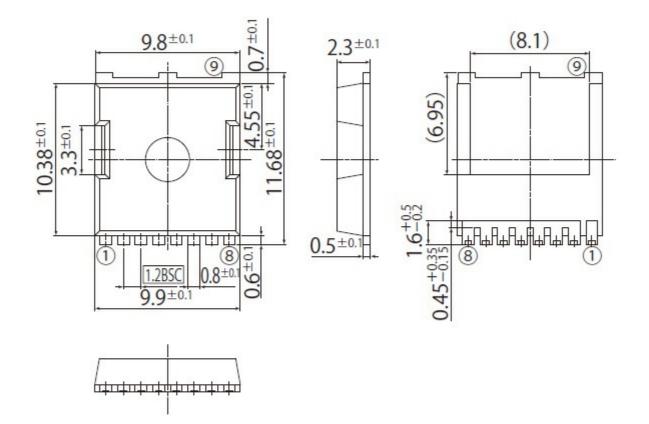






unit:mm

G9	JEDEC Code	MO-299B		
	JEITA Code	-		
	House Name	LG(TOLL)		



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[Specific applications]

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